

Kent Academic Repository

Full text document (pdf)

Citation for published version

Volcke, C. and Gandhiraman, R.P. and Gubala, V. and Doyle, C. and Fonder, G. and Thiry, P.A. and Cafolla, A.A. and James, B. and Williams, D.E. (2010) Plasma functionalization of AFM tips for measurement of chemical interactions. *Journal of Colloid and Interface Science*, 348 (2). pp. 322-328. ISSN 0021-9797.

DOI

<https://doi.org/10.1016/j.jcis.2010.04.042>

Link to record in KAR

<http://kar.kent.ac.uk/45237/>

Document Version

Author's Accepted Manuscript

Copyright & reuse

Content in the Kent Academic Repository is made available for research purposes. Unless otherwise stated all content is protected by copyright and in the absence of an open licence (eg Creative Commons), permissions for further reuse of content should be sought from the publisher, author or other copyright holder.

Versions of research

The version in the Kent Academic Repository may differ from the final published version.

Users are advised to check <http://kar.kent.ac.uk> for the status of the paper. **Users should always cite the published version of record.**

Enquiries

For any further enquiries regarding the licence status of this document, please contact:

researchsupport@kent.ac.uk

If you believe this document infringes copyright then please contact the KAR admin team with the take-down information provided at <http://kar.kent.ac.uk/contact.html>

Plasma functionalization of AFM tips for measurement of chemical interactions

Cedric Volcke^{1,2,*}, Ram Prasad Gandhiraman¹, Vladimir Gubala¹, Colin Doyle³, G. Fonder⁴,
Paul A. Thiry², Attilio A. Cafolla^{1,5}, Bryony James³ and David E. Williams^{1,6}

¹ Biomedical Diagnostics Institute (BDI), Dublin City University, Collins Avenue, Glasnevin, Dublin 9, Ireland.

² Research Centre in Physics of Matter and Radiation (PMR), University of Namur (FUNDP), 61 rue de
Bruxelles, B-5000 Namur, Belgium.

³ Research Centre for Surface and Materials Science, Department of Chemical and Materials Engineering,
University of Auckland, Private Bag 92019, Auckland 1142, New Zealand.

⁴ Laboratory of Chemistry and Electrochemistry of Surfaces (CES), University of Namur (FUNDP), 61 Rue de
Bruxelles, B-5000 Namur, Belgium.

⁵ School of Physics, Dublin City University, Collins Avenue, Glasnevin, Dublin 9, Ireland.

⁶ MacDiarmid Institute for Advanced Materials and Nanotechnology, Department of Chemistry, University of
Auckland, Private Bag 92019, Auckland 1142, New Zealand

ABSTRACT

In this paper, a new, fast, reproducible technique for atomic force microscopy (AFM) tips functionalization used for chemical interaction measurements is described. Precisely, the deposition of an aminated precursor is performed through plasma enhanced chemical vapour deposition (PECVD) in order to create amine functional groups on the AFM tip and cantilever. The advantages of the precursor, aminopropyltriethoxysilane (APTES), were recently demonstrated for amine layer formation through PECVD deposition on polymeric surfaces. We extended this procedure to functionalize AFM probes. Titration force spectroscopy highlights the successful functionalization of AFM tips as well as their stability and use under different environmental conditions.

Keywords: Force spectroscopy, Amine, PECVD, Titration force spectroscopy

* To whom correspondence should be addressed. E-mail : cedric.volcke@fundp.ac.be

Introduction

1
2
3
4 During the last two decades, scanning probe microscopies (SPM) progressively became
5
6 essential techniques in a variety of domains, ranging not only from chemistry [1], surface
7
8 physics [2] to biology [3] but also food and agricultural research [4], biomedical and
9
10 biosensor devices [5], or pharmaceutical industry [6]. Originally composed of two members,
11
12 i.e. scanning tunnelling microscope (STM) and atomic force microscope (AFM) [7], the SPM
13
14 family rapidly extended through the development of AFM derived techniques such as
15
16 amongst others: lateral force microscopy (LFM) [8], chemical force microscopy (CFM) [9],
17
18 electric and magnetic force microscopy (EFM and MFM) [10], force spectroscopy (FS) [11],
19
20 kelvin probe force microscopy (KFM) [12], molecular recognition force microscopy (MRFM)
21
22 [13-14]...

23
24
25
26
27
28
29
30 Some of those techniques are providing chemical and biological informations through
31
32 judicious use of chemical and biological interactions. For example, appropriate
33
34 functionalization of STM tips was previously used to identify functional groups inside
35
36 molecules organized in self-assembled monolayers at liquid-solid interfaces [15]. Similar
37
38 technique discriminates bases in DNA molecules [16]. In atomic force microscopy derivative
39
40 such probe modifications were extensively used to identify and quantify chemical and
41
42 biological interactions [17]. For example, chemical force microscopy reveals specific
43
44 chemical functionality at the nanoscale by using chemically modified AFM probes [18]. In
45
46 such a case, hydrogen-bonding and/or hydrophobic interactions are governing the probe-
47
48 surface interaction, providing chemical contrast in the resulting SPM images. In molecular
49
50 recognition force microscopy, attachment of antibody at the tip apex allowed the
51
52 identification and localisation of recognition events between antibody on the probe and
53
54 antigens deposited at surfaces [14].
55
56
57
58
59
60
61
62
63
64
65

1
2 Generally, those AFM probe modifications require the presence of functional groups like
3
4 carboxylic or amino groups at the tip apex. The attachment of alkanethiol self-assembled
5
6 monolayers (SAMs) onto gold (or platinum) coated AFM probes is the most commonly used
7
8 probe modification technique [19]. However, this latter procedure is detrimental to some
9
10 important experimental parameters such as tip radius of curvature, for example. Moreover,
11
12 alkanethiol SAMs formation on gold coated AFM probes is mostly performed in liquid-phase.
13
14 Such procedure may use hazardous materials producing liquid wastes environmentally non
15
16 friendly. Also, these are relatively time-consuming. Finally, SAMs stability may reduce probe
17
18 lifetime. Organosilane functionalization of silicon or silicon nitride tips is another possibility
19
20 although not really explored [20]. This can originate from the fact that liquid-phase deposition
21
22 of silane is well-known to produce fairly thick polymeric layer.
23
24
25
26
27
28
29
30

31 In such cases, gas-phase deposition process can be a good alternative. Although not exposed
32
33 in literature, it resolves major issues arising from liquid-phase deposition process.
34
35 Particularly, plasma enhanced chemical vapour deposition (PECVD) retained our attention.
36
37 Indeed, it is a versatile surface engineering technique which had proven to be an excellent tool
38
39 for surface modification and large scale industrial production [21]. Moreover, it enables rapid,
40
41 low-temperature deposition of various functional groups in a controlled way on a large variety
42
43 of substrates including complex three-dimensional structures [22]. In this technique, a plasma
44
45 discharge is created in presence of a precursor containing the required chemical groups. The
46
47 deposited coatings are uniformly dispersed, with a precise control on thickness.
48
49
50
51
52
53
54
55

56 This technique has previously been used to modify substrates such as glass, silicon or
57
58 polymers in order to monitor their surface properties. For example, hexamethyldisiloxane
59
60
61
62
63
64
65

1 (HMDSO) PECVD deposited coatings were used to tailor hydrophilic property of polymeric
2 surfaces [23]. Also, amino-functionalization of surfaces has previously been demonstrated
3
4 using PECVD from ethylene diamine (EDA) or allylamine precursor on glass, silicon or
5
6 polypropylene [24-25]. Recently, an alternative precursor, (3-aminopropyl)triethoxysilane
7
8 (APTES), was highlighted as appropriate for cycloolefin copolymers amination [26-27]. Due
9
10 to the presence of Si-O groups this molecule is creating chemical bonding to plasma activated
11
12 surfaces, allowing a good adhesion, stability and high amino-content of the coating.
13
14
15
16
17
18

19 However, up to now, PECVD deposition of aminated precursor on AFM probes in order to
20
21 functionalize them for chemical applications (as CFM or FS) was not explored. In this paper,
22
23 we propose to fill this gap by demonstrating the amino functionalization of AFM probes
24
25 through PECVD deposition of APTES precursor. The coating is first characterised using X-
26
27 ray photoelectron spectroscopy (XPS), ellipsometry, dual polarization interferometry (DPI),
28
29 water contact angle (WCA) measurements and AFM imaging. The probe functionalization
30
31 and coating stability is analyzed through chemical force spectroscopy and chemical force
32
33 titration measurements.
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

Materials and Methods

Materials

3-aminopropyltriethoxysilane (APTES), hydrochloric acid (HCl), high purity HPLC grade water and sodium hydroxide (NaOH) were purchased from Sigma Aldrich and used without further treatment. Hyperpure silicon polished (100) n-doped silicon substrates were provided by Wacker Chemitronic GmbH.

The PECVD system

The experiment was carried out in a computer controlled PECVD reactor Europlasma, model CD300 (Oudenaarde, Ghent, Belgium). An aluminium vacuum chamber, connected to a Dressler's CESAR 136 RF power source (Munsterau, Stolberg, Germany) with an operating frequency of 13.56 MHz with an automated match-box was used. The chamber details are described elsewhere [22, 23, 28]. The AFM probes were placed at a floating electrode and the input power was fixed at 14 watt. The powered electrode, a 24 cm x 21 cm plate with a 6 cm diameter hole in the middle, was placed slightly below the top of the chamber and the chamber wall was grounded. The powered electrode is cooled with running water. Also a 24 cm x 21 cm x 1.2 cm electrically isolated, water cooled hollow metallic setup placed 10 cm away from the powered electrode is used as the substrate holder. The powered electrode (PE) is separated from the ground chamber by ceramic spacers and a floating potential (FP) electrode is placed under the powered electrode. The APTES precursor was stored in a KF25 closed nipple connected to the chamber through a needle valve. The needle valve was used to control the flow of precursor APTES vapors. As the vapor pressure of APTES is less than 10 Torr at 1000° C, the APTES container was heated at 80° C and to prevent condensation of

1 APTES in pipelines, the stainless steel supply lines from source to vacuum chamber were also
2 heated at 80° C through a temperature controlled heating tape.
3
4

5 **Surface preparation**

6
7
8 AFM probes and silicon plates were first cleaned with dry air before being loaded in the
9 plasma chamber. The chamber was pumped down to a base pressure of 20 mTorr. Prior to the
10 deposition, plasma cleaning and activation was carried out using argon (50 sccm) + oxygen
11 (50 sccm) mixed plasma (250 watt RF power). After three minutes, the oxygen flow was
12 closed and the RF power reduced to 14 watt. APTES is then introduced in the chamber during
13 the required deposition time of 30 seconds. A short deposition time was used because a very
14 thin coating was required. The operating pressure is ~ 70 mTorr. The APTES supply is then
15 closed and plasma RF power shut down.
16
17
18
19
20
21
22
23
24
25
26
27
28
29

30 **Surface characterization**

31 Ellipsometry

32
33
34
35 The thickness of the APTES coating on silicon wafer was characterized using J.A. Woollam
36 Co., Inc EC-400, M-2000UI Spectroscopic Ellipsometer. All layers were modeled as a simple
37 silicon dioxide dispersion layer to extract an effective thickness.
38
39
40
41

42 Contact angle

43
44
45 The film wettability is analysed by measuring the water contact angle (WCA) of the film
46 surface using a VCA 2500 XE contact angle meter on a 2.5 µl solution drops that were
47 allowed to equilibrate at room temperature in ambient atmosphere during 15 to 30 s. Water
48 used in these experiments was deionised (18 MΩ cm resistivity) with a Millipore Milli-Q
49 filtration system. Unbuffered, constant low ionic-strength solutions (10^{-2} M) of HCl and
50 NaOH were freshly prepared and used to control the pH. Mean contact angle values obtained
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

1 on 3 different measurements at different places on the sample surface. Experiments were
2 reproduced at least 3 times on several samples.
3
4
5
6

7 Atomic force microscopy imaging (AFM)

8

9 AFM examinations are performed in ambient air with a commercial microscope (Dimension
10 3100 controlled by a Nanoscope IIIa controller, Digital Instruments, Santa-Barbara – CA,
11 USA), in the Tapping-Mode™, using standard unmodified silicon cantilevers
12 (BudgetSensors®, Bulgaria) with a 7 nm radius of curvature and a 42 N.m⁻¹ spring constant
13 (nominal values). Topographic images are recorded at a scanning rate of 1-2 Hz, and a
14 resonance frequency of about 300 kHz (nominal value). The background slope is resolved
15 using first order polynomial function. No further filtering is performed. The surface roughness
16 of silicon substrates and PECVD deposited APTES layer on silicon substrate is evaluated over
17 3 images (2 μm x 2 μm) and the standard deviation is then calculated. The root-mean-square
18 roughness (Rrms) considered is defined as the average of height deviations taken from the
19 mean plane [29].
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38

39 X-ray photoelectron spectroscopy (XPS)

40

41 The XPS data were collected on a Kratos Axis UltraDLD equipped with a hemispherical
42 electron energy analyser. Spectra were excited using monochromatic Al Kα X-rays (1486.69
43 eV) with the X-ray source operating at 100 W. This instrument illuminates a large area on the
44 surface and then using hybrid magnetic and electrostatic lenses collects photoelectrons from a
45 desired location on the surface. In this case the analysis area was a 220 μm by 220 μm spot.
46 The measurements were carried out in normal emission geometry. Survey scans were
47 collected with 160 eV pass energy, whilst core level scans were collected with pass energy of
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

20 eV. The analysis chamber was at pressures in the 10^{-9} Torr range throughout the data collection.

Data analysis was performed using CasaXPS (www.casaXPS.com). Shirley backgrounds were used in the peak fitting. Quantification of survey scans utilised relative sensitivity factors supplied with the instrument. Core level data were fitted using Gaussian-Lorentzian peaks (30 % Lorentzian). The elements present in the coating C, N, O, Si were detected using the XPS survey scan, (Supporting informations). High resolution scans of individual core levels show the various bonding states.

Chemical Force Titration (CFT)

Commercial triangular silicon nitride cantilevers (BudgetSensors®, Bulgaria) with 0.06 N/m spring constant and 7 nm radius of curvature (nominal values) were functionalized by APTES molecules through PECVD deposition process as described above. Water used in these experiments was deionised (18 M Ω cm resistivity) with a Millipore Milli-Q filtration system. Unbuffered, constant low ionic-strength solutions (10^{-2} M) of HCl and NaOH were freshly prepared and used to control the pH. The probe tips and functionalized surfaces were immersed in a droplet of a given pH solution.

The force measurements were performed on a commercial microscope (MultiMode AFM equipped with a Nanoscope IIIa electronics and a liquid cell, Digital Instruments, Santa-Barbara, CA). Adhesion force values were obtained from ~ 100 force-distance curves per pH value in several different places on the sample. Each force-distance curve was obtained with a Z scan size of ~ 500 nm and a scan rate of 1 cycle/s. All measurements were made using the same AFM probe. Measurements were made by alternating from high to low and from low to high pH to check the stability of the surface and the tip as a function of time. The tip and

1 substrate were rinsed with deionized water and dried in a stream of nitrogen before each pH
2 change. Experiments were reproduced at least 3 times on several samples. The pull-off force
3 values were calculating using the Scanning Probe Image Processor software (SPIP™, Image
4 Metrology). Averaged adhesion values were determined from Gaussian fits on histograms of
5 the adhesion values obtained from ~ 100 individual force-versus-distance curves, and the
6 reported errors correspond to the standard deviations.
7
8
9
10
11
12
13
14
15
16

17 Dual Polarization Interferometry (DPI)

18
19
20
21 The dual polarization interferometry, an optical sensing technique was carried out using a
22 Farfield AnaLight® instrument. The surface used was a silicon oxynitride AnaChip™ and the
23 temperature was controlled throughout to 20° C. The structural changes taking place with the
24 addition of a surfactant are investigated by monitoring the refractive index, thickness and
25 mass variations with the addition of PBS Tween®. The Silicon oxynitride AnaChip™
26 consists of two optical waveguides that confine light into defined boundaries, one stacked on
27 top of the other separated by an insulated layer. The substrate is silicon wafer and the
28 waveguides are silicon dioxide doped with silicon nitride. A collimated light beam from a
29 helium-neon laser (wavelength 632.8 nm) is first passed through a ferroelectric liquid crystal
30 ½ wave plate to create plane polarized light. The liquid crystal is switched such that during
31 one half of the measurement transverse magnetic phase is passed through the waveguide and
32 during the other half measurement transverse electric phase is passed through. When the laser
33 beam is passed through the edge of the sensor chip, it propagates through both waveguides.
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

The two beams diverge and form a Young's interference pattern at the side of the chip in far-field. The top wave guide that is exposed to the analyte is a sensing waveguide and the speed of the light travelling through it will change if the molecules are attached or removed from it. The light travelling through the bottom waveguide is unaffected and progresses at a constant

1 velocity and it acts as an optical reference. The interference pattern represents the relative
2 phase position of the upper and lower modes at the output face of the device. The precise
3 positions of the light and dark bands depend upon the phase relationship of the light as it
4 emerges from the two waveguides. An addition or removal of material from the top surface of
5 the sensing waveguide would result in a shift of the interference fringe position. The phase
6 change is due to a variation in the top sensing waveguide. As the refractive index of the lower
7 reference waveguide is unaffected, the phase shift is related solely to the change observed in
8 the sensing waveguide. Based on the details of the phase shift, a range of layer thicknesses
9 and refractive index values can be calculated.
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

Results and discussions

Coating characteristics

APTES coatings were first deposited on silicon substrates through PECVD deposition under 14 watt RF plasma power and 30 s deposition time. The mean coating thickness is about 5.2 nm, as measured by ellipsometry. Concerning the coating thickness on the AFM probe, as we did not find a way to directly measure it, we simply assumed that the characteristics of the coating on the tip are very close to the same coating deposited on a silicon wafer. This assumption is also considered for coating hydrophilicity measurements. In such a case, water contact angle (WCA) is around $54^\circ \pm 1$, a value similar to that found in literature for liquid-phase deposited APTES on silicon oxide surfaces, as well as APTES PECVD deposited on polymeric surfaces [26-27, 30]. This change in film wettability is a confirmation of successful surface chemistry modification.

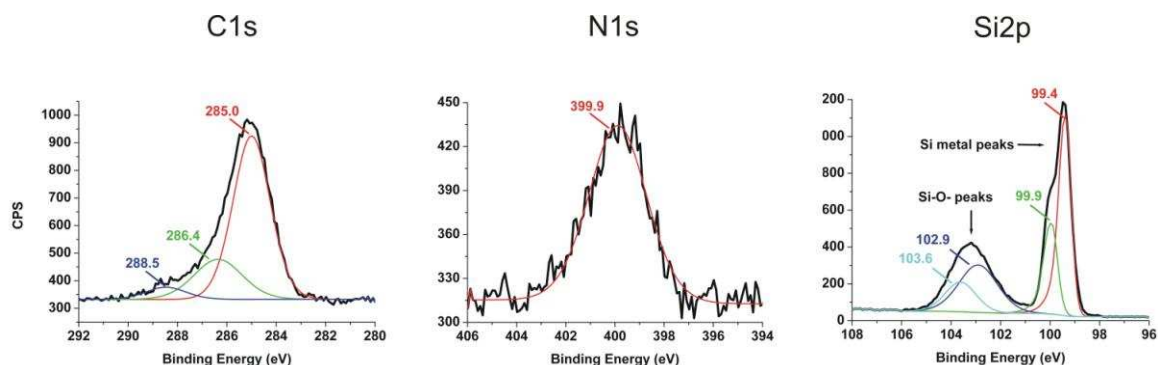


Figure 1. High resolution core level photoemission spectra of (a) C 1s (b) N 1s (c) Si 2p, taken with a pass energy of 20 eV using monochromatic Al K α monochromatic X-rays (1486.69 eV), with the X-ray source operating at 100 W. The analysis area was a 220 by 220 micron spot. The measurements were carried out in normal emission geometry. The core level peaks are deconvoluted to show the various bonding environments. Data analysis was performed using CasaXPS (www.casaXPS.com). Shirley backgrounds were used in the peak fitting. Core level data were fitted using Gaussian-Lorentzian peaks (30 % Lorentzian).

1 The chemical composition of coatings is determined through X-ray photoelectron
2 spectroscopic analysis (Fig. 1). The presence of carbon, oxygen, silicon and nitrogen species
3 in the coating is highlighted in the XPS survey spectrum (Supporting Informations).
4 Qualitatively, the C1s spectrum (Fig. 1, left) was deconvoluted with three main contributions:
5 at 285.0, 286.4 and 288.5 eV, which are attributed to aliphatic carbon, C-N and C-O-NH₂
6 species, respectively [31]. The N1s region highlights one peak centred at 399.9 eV and can be
7 attributed to the presence of NH₂ groups (Fig. 1, centre) [31]. The Si2p spectrum is
8 deconvoluted using 4 contributions: two associated to pure silicon (Si2p_{1/2} at 99.4 eV and
9 Si2p_{3/2} at 99.9 eV) and two associated to silicon oxide Si-O- (Si2p_{1/2} at 103.6 eV and Si2p_{3/2}
10 at 102.9 eV) (Fig. 1, right) [31]. The observation of signals attributable to elemental Si, the
11 substrate, implies that, at least in parts over the surface, the coating was of thickness
12 commensurate with the escape depth of the photoelectrons: a few nm at most. Moreover, the
13 nitrogen/carbon ratio extracted from XPS data (0.12) is almost identical to the N/C ratio of the
14 monomer (0.11). Thus, the coating can be expected to present a significant number of
15 hydrophilic amino groups at the surface in addition to hydrocarbon fragments, as confirming
16 WCA data.
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40

41 The interfacial coating properties were analyzed using DPI. By defining the waveguide
42 structure with alternate polarizations both the refractive index and the thickness of adsorbed
43 layers at the substrate (solid) – liquid interface were determined. Information about the mass
44 and the density of the film was derived, based on which the amount of amino groups for each
45 sample was calculated, assuming that the silane does not fragment but retains its molecular
46 identity. Therefore, from the mass of the film per cm² and the molar mass of the monomer,
47 the number of moles of –NH₂ in the film per cm² of geometric area can be calculated. DPI
48 allowed monitoring the layer composition of the coated slide before and after a treatment with
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

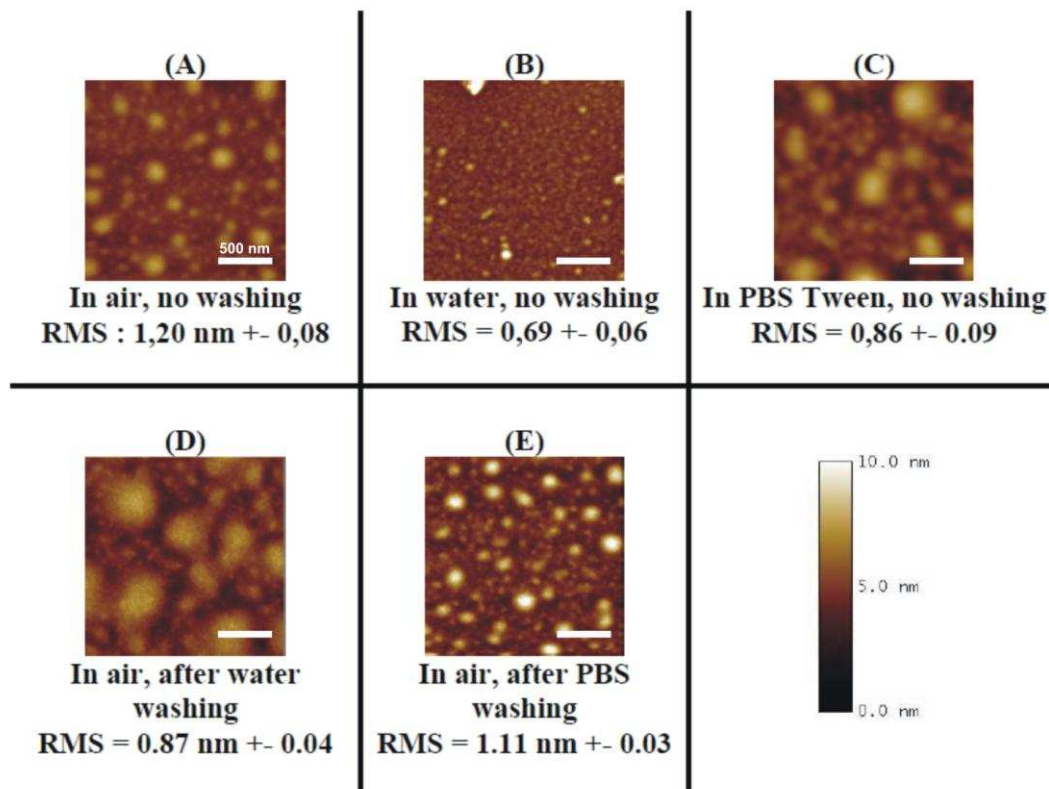
1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

1% w/v solution of PBS Tween (PBST) to probe the film adhesion and the structural changes upon washing with a detergent. This technique revealed that the APTES coatings undergo a small swelling when in contact with PBS buffer, which is reflected in the increased thickness of the layer from 5.12 to 6.39 nm. PBS Tween treatment leaves the APTES film virtually unaffected, keeping the APTES mass constant at 3.80 ng / mm². The averaged number of amino groups is estimated around 16.7×10^{14} /cm² before and after treatment with PBS Tween® [27]. This value is about 3-4 times higher than what is observed for APTES layers deposited through traditional liquid-phase technique on silicon substrates [25, 32]. We can also notice that the coating height measure through ellipsometry (5.2 nm) and DPI (5.12 nm) experiments are in very good agreement, highlighting the reproducibility of the deposition process.

Stability/change in coating surface structure in liquids is checked through AFM imaging. Tapping-Mode™ topographical (TM-AFM) images were performed in air, under DI water and under PBS Tween®. As observed in Fig. 2A, APTES coating in air exhibits globular structures in the range of 50-200 nm in diameter and below 10 nm in height. These structures can originate from polymerisation of APTES molecules on the silicon surface. This fact is usually observed while water is present during the liquid-phase deposition process. Here, the APTES precursor is not 100% anhydrous and also it is exposed to atmosphere while transferring to the source container, which could have resulted in absorption of moisture content from atmosphere. This could therefore lead to the formation of the observed structures. The surface roughness (rms) is measured as being ~ 1.2 nm. However, while imaged under DI water, the same surface appears more flat and homogeneous with a mean roughness around 0.7 nm (Fig. 2B). Swelling of the surface, as also deduced from DPI data, can explain these surface modifications. Unbound, physisorbed APTES molecules (or fragments), washed away by the water environment, can also explain the disappearing of the

1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42

globular features. While imaged under PBS Tween® environment (Fig. 2C), APTES coating are also revealing globular structures. However, these ones appears bigger (200-400 nm in diameter) and more dispersed. Their heights are still below 10 nm, rendering a mean roughness value around 0.9 nm.



43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

Figure 2. Tapping-Mode AFM topographical imaging (2 μm x 2 μm) of PECVD deposited APTES coating on silicon wafer in diverse environment: (A) in air, (B) in DI water, (C) in PBS Tween®, (D) in air after washing with DI water and drying in air, (E) in air after washing with PBS Tween® and drying in air. RMS roughness values are also indicated. (Bottom right) Z-scale color bar.

In order to determine the origin of such surface topographical changes, some more experiments were performed. Imaging is done in air, before and after washing with DI water and PBS Tween® (Figs 2D and 2E, respectively). A water wash and an imaging in air after drying reveals globular structures (Fig. 2D). Their characteristics are about 300-500 nm in diameter and around 3 nm in height. Washing with water and blow drying with N₂ flow could

1 have resulted in removal of partly or loosely bound particles. The change in film density with
2 removal of molecules could result in a significant change in morphology. A swelling effect
3 due to residual and or atmospheric water on the surface is again privileged in order to explain
4 the observed globular structures, although a non-significant polymerization effect can not
5 totally be discarded.
6
7

8
9
10
11 After a PBS Tween® treatment, the coating surface still presents globular structures (100-200
12 nm in diameter and 5-7 nm in height) (Fig. 2E). Those observations also correlate to a
13 swelling of the deposited coating. However, it appears to be less pronounced than in water
14 due to presence of ions in solution, probably getting tendency to get attached to the structures.
15
16 Also, the presence of Tween®, acting as a detergent, in the PBS solution could result in the
17 decreased size of globular structures at the coating surface after PBS-Tween® washing.
18
19
20
21
22
23
24
25
26
27

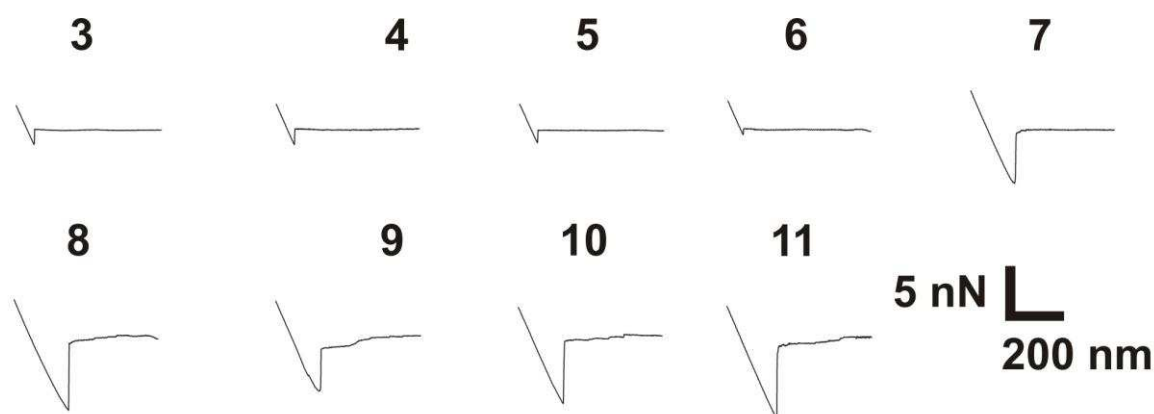
28
29 At this stage, we can therefore confirm the deposition of an APTES coating (~ 5.2 nm thick),
30 presenting a high density of surface amino groups, fairly stable and reproducible. Moreover,
31 coating surface roughness is relatively small in water, making those appropriate for chemical
32 force microscopy measurements in aqueous solutions while deposited onto AFM probes.
33
34
35
36
37
38
39
40
41

42 ***Application to chemical force titration***

43
44
45
46
47

48 In order to check the efficient functionalization of the three-dimensional AFM probes by
49 PECVD deposition of APTES precursor, and also to demonstrate their applicability to
50 chemical interaction measurements, chemical force titration experiments were performed. In
51 such “force titration” measurements, the chemical adhesion (under liquid environment)
52 between a modified AFM tip and a similarly modified sample surface is monitored as a
53 function of the solution pH.
54
55
56
57
58
59
60
61
62
63
64
65

1
 2 By performing pH dependent force-distance curves, the contribution of the ionisable
 3
 4 functional groups, i.e., amino groups can be studied separately. In aqueous solutions, the sum
 5
 6 of the different attractive forces is counteracted by the electrostatic repulsion of protonated
 7
 8 amino groups if pH is close to or lower than the pK_a of these groups. Thus, in such systems,
 9
 10 the balance between attractive forces and repulsive electrostatic forces is measured as a force-
 11
 12 distance curve. This technique has previously been used to characterize the interactions
 13
 14 between tips and sample substrates modified with carboxylic acid, amine and phosphonic acid
 15
 16 groups [33-38]. Most of those studies focused on systems in which both tip and samples were
 17
 18 functionalized by liquid phase deposition using alkanethiols on gold, for example. We
 19
 20 propose to use our modified probe with this technique. Experiments were performed at fixed
 21
 22 ionic strength, as it is known to drastically modify forces measured [33, 36-37, 39]. To ensure
 23
 24 the comparability of the data obtained at different pH solutions, one tip was used throughout
 25
 26 one set of force titration experiments. Experiments are then reproduced different times with
 27
 28 different tips.
 29
 30
 31
 32
 33
 34



35
 36
 37
 38
 39
 40
 41
 42
 43
 44
 45
 46
 47
 48
 49
 50
 51
 52 **Figure 3.** Representative retraction force curves for NH_2 terminated tips and NH_2 modified substrate surface in
 53 different pH solutions. Upper number indicates pH of the solution during experiment.
 54
 55
 56

57 Fig.3 shows typical retraction force curves between APTES plasma modified AFM tip and
 58 similarly modified silicon surfaces at different pH between 3 and 11 in fixed 10^{-2} M ionic
 59
 60
 61
 62
 63
 64
 65

1 strength solutions. Pull-on (black) as well as pull-off forces (red) clearly highlight variations
2 with pH. In this paper, we only focus on pull-off forces (adhesion forces) measured through
3 retraction force curves.
4
5

6
7 Average adhesion force values obtained at different solution pH values (~ 100 individual
8 force measurements for each pH value, obtained at three different positions on sample
9 surface) for tip and sample functionalized with PECVD deposited APTES are plotted in Fig.
10
11
12
13
14 4. In these averaged pH-dependent force measurements, a pronounced dependence of the
15 magnitude of the averaged pull-off forces on the pH was highlighted. An increase in adhesive
16 force with increasing pH is observed. The averaged pull-off force exhibits behaviour similar
17 to conventional titration experiments and is consistent with protonation/deprotonation of
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

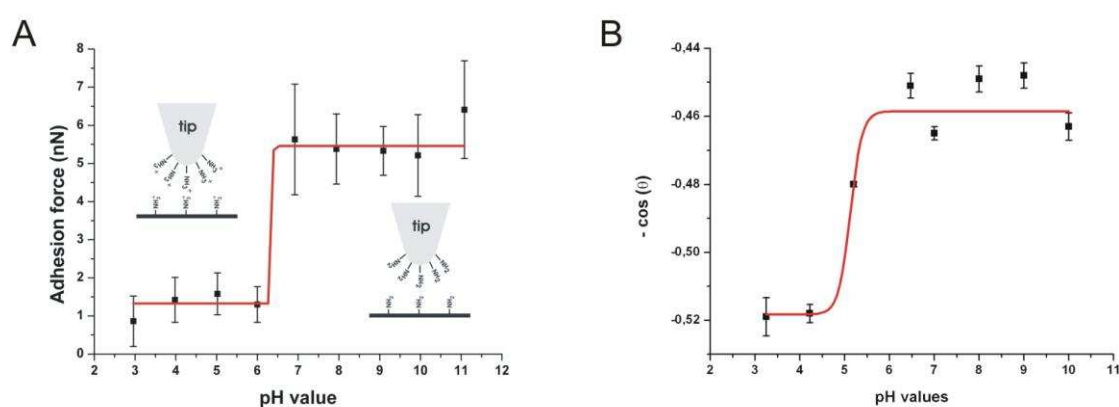


Figure 4. (A) Chemical force titration curve for tip and surface both modified with PECVD deposited APTES coating, acquired under solution of 10^{-2} M ionic strength. (The curve has been added as a guide to the eye). Schematics are presenting the proposed interactions of APTES modified tips and APTES modified surface in water at different pH values. (B) Negative cosine of the averaged contact angles of water drops on a silicon surface modified with PECVD deposited APTES as a function of pH.

1 For comparison, we have performed contact angle titration experiments using water solution
 2 droplets of various pH values on the PECVD deposited APTES coating on silicon surface.
 3
 4 Figure 4B exhibits the contact angle titration curve, in which 3 different measurements were
 5 performed for each pH value to obtain the mean contact angle. The contact angle remained
 6 almost stationary above pH 6.0. These data also show a sharp transition (an increase in
 7 wettability) as the droplet pH is reduced below from pH 6.0 to 4.0. An increase in wettability
 8 is expected while surface becomes more protonated. Finally contact angle became constant at
 9 pH 4.0 and below. The pKa value of this surface can be estimated at 5.2.
 10
 11
 12
 13
 14
 15
 16
 17
 18
 19
 20
 21

22 The measured adhesive forces, as presented in Fig. 4, can be used to calculate the local degree
 23 of ionization α_1 and the acid dissociation constant value pK_a extracted from it. Indeed, as
 24 theoretically described in literature [40], interaction forces between tip and surface can
 25 reasonably be described with the Johnson, Kendall, Roberts model of adhesion mechanics,
 26 known as JKR model [41]. They described the pull-off force between a sphere 1 (modelling
 27 the AFM tip) and a flat surface 2 (modelling the sample surface) in a medium 3 as:
 28
 29
 30
 31
 32
 33
 34
 35
 36

$$37 \quad F_{adh} = -(3/2) \pi R W_{12}$$

38 with R, the AFM tip radius of curvature and W_{12} is the work of adhesion needed to pull the tip
 39 off the sample surface. The work of adhesion W_{12} can be expressed in term of γ_{13} (the tip-
 40 surface free energy in equilibrium with the medium), γ_{23} (the substrate-surface free energy in
 41 equilibrium with the medium) and γ_{12} (the interfacial free energy of the tip-substrate interface)
 42 such as: $W_{12} = \gamma_{13} + \gamma_{23} - \gamma_{12}$. If tip and sample surface are identically functionalized (with
 43 NH_2 groups for example), the work of cohesion can be expressed as $W_{12} = 2 \gamma_{LS}$, where $\gamma_{LS} =$
 44 $\gamma_{13} = \gamma_{23}$ is the surface free energy of the particular surface functionality against the medium,
 45 the interfacial free energy γ_{12} being zero. Moreover, the degree of ionization of surfacial
 46 amine functional groups is given by the relationship:
 47
 48
 49
 50
 51
 52
 53
 54
 55
 56
 57
 58
 59
 60
 61
 62
 63
 64
 65

$$\alpha_i = [\text{NH}_3^+] / ([\text{NH}_3^+] + [\text{NH}_2])$$

If we assume that changes in γ_{LS} ($\delta\gamma_{\text{LS}}$) with pH variations only depend linearly on the fraction of amino groups NH_2 converted to NH_3^+ , the degree of ionization α_i can be related to γ_{LS} at limiting values of pH(x) for which the surface is fully protonated (pH(3)) and completely ionized (pH(11)). As γ_{LS} is directly proportional to the measured adhesion force, we can finally describe α_i as:

$$\alpha_i(\text{pH}(x)) = [\text{F}_{\text{adh}}(\text{pH}(3)) - \text{F}_{\text{adh}}(\text{pH}(x))] / [\text{F}_{\text{adh}}(\text{pH}(3)) - \text{F}_{\text{adh}}(\text{pH}(11))].$$

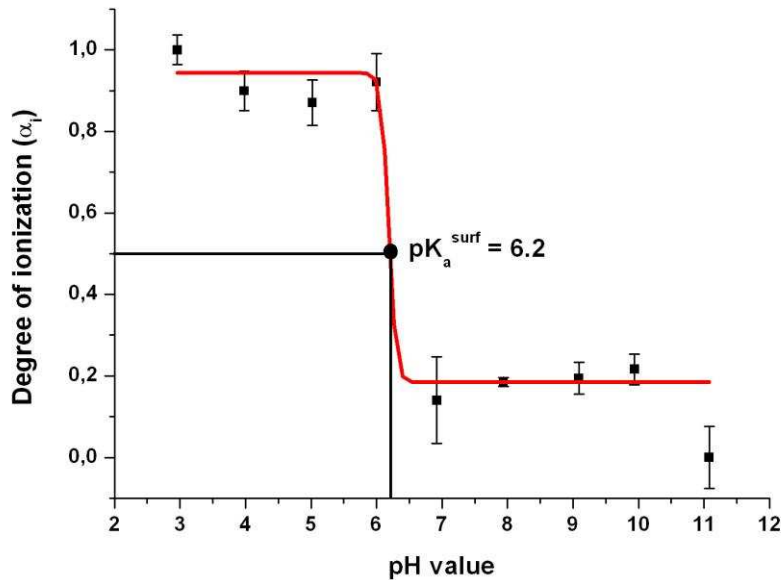


Figure 5. Degree of ionization α_i as a function of the pH calculated on the basis of the adhesion forces (Fig. 4).

We can therefore use this equation to calculate the degree of ionization for amino groups from the adhesion force values presented in Figure 4. Variations in surface ionization are presented in Figure 5. It can be used to determine the acid dissociation constant pK_a , defined as the pH at which $\alpha_i = 1/2$. Experimentally, the surficial amino groups' pK_a (i.e. $\text{pK}_a^{\text{surf}}$) is estimated at a value of 6.2, close to the value deduced from contact angle titration. Hence, local force microscopy measurements using modified AFM probes and macroscopic wetting studies

1 provide very similar values for the pK_a of the surface amino groups. We can however notice
2 that the pK_a^{surf} obtained shifts of about 4-5 pH units to lower pK_a values compared to the pK_a
3 of free organic primary amines (pK_a ~ 10-11) [35, 42] in aqueous solution. Similar shifts to
4 lower values were previously observed experimentally and related to the hydrophobicity of
5 the local environment of the corresponding functional groups. Results indicate that the local
6 environment of amino groups in the coating is somewhat hydrophobic. Upon lowering the pH,
7 NH₂ groups will resist protonation since stabilisation of the charge is low in the (hydrophobic)
8 environment. This causes a shift of the pK_a^{surf} to lower value. In general, this interpretation is
9 corroborated by simulations [43].
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

Conclusion

In conclusion, we demonstrated a new, fast, reproducible technique to atomic force microscopy (AFM) tip functionalization for chemical interactions measurement. PECVD deposited amino-coatings were extensively characterised using XPS, AFM, contact angle, ellispometry and DPI measurements. Data highlighted the deposition, surface characteristics and stability of the coating. Moreover, a high amount of amine functional groups at coating surface was revealed. Their application in chemical interaction measurements through chemical force titration particularly demonstrated the successful functionalization of AFM tips as well as their stability and use under different environmental conditions.

1 **Acknowledgment**
2
3
4
5
6

7 This material is based upon works supported by the Science Foundation Ireland under Grant
8
9 No. 05/CE3/B754. C.V. is a postdoctoral researcher of the Belgian Fund for Scientific
10
11 Research (F.R.S. / F.N.R.S.). D.E.W. is an E.T.S. Walton visiting fellow of Science
12
13 Foundation Ireland.
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

References

- [1] Y. Sugimoto, P. Pou, M. Abe, P. Jelinek, R. Perez, S. Morita, O. Custance, *Nature* 446 (2007) 64; R. McKendry, M.-E. Theoclitou, T. Rayment, C. Abell, *Nature* 1998, 391, 566; R.W. Friddle, M.C. Lemieux, G. Cicero, A.B. Artyukhin, V.V. Tsukruk, J.C. Grossman, G. Galli, A. Noy, *Nat. Nanotechnol.* 2 (2007) 692.
- [2] B. Bhushan, J.N. Israelachvili, U. Landman, *Nature* 374 (2002) 607; M. Fiebig, Th. Lottermoser, D. Fröhlich, A.V. Goltsev, R.V. Pisarev, *Nature* 419 (2002) 818.
- [3] Y.F. Dufrêne, *Nat. Rev. Microbiol.* 2004, 2, 451; C. Volcke, S. Piroton, Ch. Grandfils, C. Humbert, P.A. Thiry, I. Ydens, P. Dubois, M. Raes, *J. Biotechnol.* 125 (2006) 11.
- [4] A.R. Kirby, A.P. Gunning, V.J. Morris, *Trends Food Sci. Tech.* 6 (1995) 359.
- [5] K. Salaita, Y. Wang, C.A. Mirkin, *Nat. Nanotechnol.* 2 (2007) 145; A.M. Moulin, S.J. O'Shea, M.E. Welland, *Ultramicroscopy* 82 (2000) 23; C. Grogan, R. Raiteri, G.M. O'Connor, T.J. Glynn, V. Cunningham, M. Kane, M. Charlton, D. Leech, *Biosens. Bioelectron.* 17 (2002) 201.
- [6] C. Grégoire, S. Marco, J. Thimonier, L. Duplan, E. Laurine, J.-P. Chauvin, B. Michel, V. Peyrot, J.M. Verdier, *EMBO J.* 20 (2001) 3313.
- [7] G. Binnig, H. Rohrer, C. Gerber, E. Weibel, *Phys. Rev. Lett.* 49 (1982) 57; Binnig, H. Rohrer, C. Gerber, E. Weibel, *Appl. Phys. Lett.* 40 (1982) 178; G. Binnig, H. Rohrer, *Helv. Phys. Acta* 55 (1982) 726; G. Binnig, C.F. Quate, Ch. Gerber, *Phys. Rev. Lett.* 56 (1986) 930.
- [8] R.M. Overney, E. Meyer, J. Frommer, D. Brodbeck, R. Luthi, L. Howald, H.J. Guntherodt, M. Fujihira, H. Takano, Y. Gotoh, *Nature* 359 (1992) 133; D.R. Baselt, J.D. Baldeschwieler, *J. Vac. Sci. Technol. B* 10 (1992) 2316.
- [9] C.D. Frisbie, L.F. Rozsnyai, A. Noy, M.S. Wrighton, C.M. Lieber, *Science* 265 (1994) 2071.
- [10] F. Bergasa, J.J. Saenz, *Ultramicroscopy* 42 (1992) 1189; Y. Leng, C.C. Williams, *Colloid Surf. A-Physicochem. Eng. Asp.* 93 (1994) 335; J.J. Saenz, N. Garcia, J.C. Slonczewski, *Appl. Phys. Lett.* 53 (1988) 1449; H.J. Mamin, D. Rugar, J.E. Stern, R.E. Fontana, P. Kasiraj, *Appl. Phys. Lett.* 55 (1989) 318.
- [11] M. Rief, F. Oesterhelt, B. Heymann, H.E. Gaub, *Science* 275 (1997) 1295; S.P. Jarvis, S.I. Yamamoto, H. Yamada, H. Tokumoto, J.B. Pethica, *Appl. Phys. Lett.* 70 (1997) 2238.
- [12] A.K. Henning, T. Hochwitz, J. Slinkman, J. Never, S. Hoffmann, P. Kaszuba, C. Daghljan, *J. Appl. Phys.* 77 (1995) 1888; C. Sommerhalter, T.W. Matthes, T. Glatzel, A. Jager-Waldau, M.C. Lux-Steiner, *Appl. Phys. Lett.* 75 (1999) 286.
- [13] V.P. Pastushenko, P. Hinterdorfer, F. Kienberger, C. Borken, H. Schindler, *Single Molecules* 1 (2000) 165.

1
2
3
4
5
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

[14] P. Hinterdorfer, Y.F. Dufrêne, *Nat. Methods* 3 (2006) 347.

[15] T. Ito, P. Bühlmann, Y. Umezawa, *Anal. Chem.* 70 (1998) 255; T. Ito, P. Bühlmann, Y. Umezawa, *Anal. Chem.* 71 (1999) 1699; C.Volcke, P. Simonis, F. Durant, P.A. Thiry, P. Lambin, C. Culot, C. Humbert, *Chem. Eur. J.* 11 (2005) 4185; C.Volcke, P. Simonis, P.A. Thiry, P. Lambin, C. Culot, C. Humbert, *Nanotechnology* 6 (2005) 2596; C. Volcke, P. Simonis, F. Durant, P.A. Thiry, P. Lambin, C. Culot, C. Humbert, *Physicalia Magazine* 27 (2005) 415; C. Volcke, P.A. Thiry, *J. Phys. – Conf. Series* 61 (2007) 1236; C. Volcke, P. Simonis, C. Humbert, P. Lambin, C. Culot, P.A. Thiry, *Phys. Chem. News* 36 (2007) 34.

[16] S. Chang, J. He, A. Kibel, M. Lee, O. Sankey, P. Zhand, S. Lindsay, *Nat. Nanotechnol.* 4 (2009) 297.

[17] A. Noy, *Surf. Interface Anal.* 38 (2006) 1429.

[18] A.S. Duwez, U. Jonas, H. Klein, *ChemPhysChem* 4 (2003) 1107; B.D. Beake, G.J. Legget, *Phys. Chem. Chem. Phys.* 1 (1999) 3345; M.L. Carot, V.A. Macagno, P. Paredes-Olivera, E.M. Patrito, *J. Phys. Chem. C* 111 (2007) 4294.

[19] H. Kim, J. Noh, M. Hara, H. Lee, *Ultramicroscopy* 108 (2008) 1140; H. Kim, J.H. Park, I.-H. Cho, S.-K. Kim, S.-H. Paek, H. Lee, *J. Colloid Interf. Sci.* 334 (2009) 161; F. Sato, H. Okui, U. Akiba, K. Suga, M. Fujihira, *Ultramicroscopy* 97 (2003) 303; A.-S. Duwez, B. Nysten, *Langmuir* 17 (2001) 8287; P.D. Ashby, C.M. Lieber, *J. Am. Chem. Soc.* 127 (2005) 6814; M.A. Poggi, P.T. Lillehei, L.A. Bottomley, *Chem. Mater.* 17 (2005) 4289; A. Noy, C.D. Frisbie, L.F. Rozsnyai, M.S. Wrighton, C.M. Lieber, *J. Am. Chem. Soc.* 117 (1995) 7943.

[20] T. Ito, M. Namba, P. Bühlmann, Y. Umezawa, *Langmuir* 13 (1997) 4323.

[21] P. Favia, M. Creatore, F. Palumbo, V. Colaprico and R. d'Agostino *Surf. Coat. Technol.* 142-144 (2001) 1; H. Muguruma, Y. Kase *Biosens.Bioelectron.* 22 (2006) 737.

[22] R.P. Gandhiraman, S. Daniels, D.C. Cameron, B.P. McNamara, E. Tully, R. O'Kennedy, *Surf. Coat. Technol.* 200 (2005) 1031; R.P. Gandhiraman, S. Daniels, D.C. Cameron. *Plasma Process. Polym.* 4 (2007) 369; M.M. Dudek, R. P. Gandhiraman, C. Volcke, S. Daniels, A. J. Killard, *Plasma Process. Polym.* 6 (2009) 620; A. Riaz, R.P. Gandhiraman, I.K. Dimov, L.B. Desmots, A.J. Ricco, J. Ducreé, S. Daniels, L.P. Lee, *Proceedings of the 15th International Conference on Solid-State Sensors, Actuators & Microsystems (Transducers'09)*, June 21-25, Denver, Colorado, USA, pages 1051-1054, 2009.

[23] M.M. Dudek, R.P. Gandhiraman, C. Volcke, A.A. Cafolla, S. Daniels A.J. Killard, *Langmuir* 25 (2009) 11155.

[24] D. Jung, S. Yeo, J. Kim, B. Kim, B. Jin, D.-Y. Ryu, *Surf. Coat. Technol.* 200 (2006) 2886; K. Nakanishi, H. Muguruma, I. Karube. *Anal.Chem.* 68 (1996) 1695.

[25] J. Kim, D. Jung, Y. Park, Y. Kim, D.W. Moon, T.G. Lee, *Appl. Surf. Sci.* 253 (2007) 4112.

1 [26] R.P. Gandhiraman, C. Volcke, V. Gubala, C. Doyle, L. Basabe-Desmonts, C. Dotzler,
2 M.F. Toney, M. Iacono, R.I. Nooney, S. Daniels, B. James, D.E. Williams, *J. Mat. Chem.*
3 (2010) accepted.

4 [27] C. Volcke, R.P. Gandhiraman, V. Gubala, J. Raj, Th. Cummins, G. Fonder, R.I. Nooney,
5 Z. Mekhalif, G. Herzog, S. Daniels, D.W.M. Arrigan, A.A. Cafolla, D.E. Williams, *Biosens.*
6 *Bioelectron.* (2010) DOI:10.1016/j.bios.2009.12.034.

7 [28] R.P. Gandhiraman, S.K. Karkari, S.M. Daniels, Brian McCraith. *Surf. Coat. Technol.*
8 203 (2009) 3521.

9 [29] M. Haïdopoulos, F. Mirabella, M. Horgnies, C. Volcke, P.A. Thiry, P. Rouxhet, J.-J.
10 Pireaux, *J. Microsc.-Oxf.* 228 (2007) 227.

11 [30] Y. Cho, A. Ivanisevic, *J. Phys. Chem. B* 108 (2004) 15223.

12 [31] G. Beamson and D. Briggs, *High resolution XPS of organic polymers: the Scienta*
13 *ESCA300 database*, Chichester, New York, 1992

14 [32] S. Fiorilli, P. rivolo, E. Descrovi, C. Ricciardi, L. Pasquardini, L. Lunelli, L. Vanzetti, C.
15 Pederzoli, B. Onida, E. Garonne, *J. Colloid Interf. Sci.* 321 (2008) 235–241.

16 [33] M.L. Wallwork, D.A. Smith, *Langmuir* 17 (2001) 1126.

17 [34] H.-X. He, W. Hang, H. Zhang, Q.G. Li, S.F.Y. Li, Z.F. Liu, *Langmuir* 16 (2000) 517.

18 [35] H. Zhang, H.X. He, T. Mu, Z.-F. Liu, *Thin Solid Films* 327-329 (1998) 778.

19 [36] J. Zhang, J. Kirkham, C. Robinson, M.L. Wallwork, D.A. Smith, A. Marsh, M. Wong,
20 *Anal. Chem.* 72 (2000) 1973.

21 [37] D.A. Smith, M.L. Wallwork, J. Zhang, J. Kirkham, C. Robinson, A. Marsh, M. Wong, *J.*
22 *Phys. Chem. B* 104 (2000) 8862.

23 [38] J. Wang, H. Zhang, H. He, T. Hou, Z. Li, X. Xu, *J. Mol. Struc.* 451 (1998) 295; B.
24 Wang, R.D. Oleschuk, J.H. Horton, *Langmuir* 21 (2005) 1290.

25 [39] A. Geissler, M.-F. Vallat, L. Vidal, J.-C. Voegel, J. Hemmerlé, P. Schaaf, V. Roucoules,
26 *Langmuir* 24 (2008) 4874.

27 [40] D.V. Venezov, A. Noy, L.F. Rozsnyai, C.M. Lieber *J. Am. Chem. Soc.* 119 (1997) 2006.

28 [41] K.L. Johnson, K. Kendall, A.D. Roberts *Proc. R. Soc. A* 324 (1971) 301.

29 [42] E.W. van der Vegte, G. Hadziioannou *J. Phys. Chem. B* 101 (1997) 9563; H. Schönherr,
30 M.T. van Os, Z. Hruska, J. Kurdi, R. Förch, F. Arefi-Khonsari, W. Knoll, G.J. Vancso, *Chem*
31 *Comm* (2000) 1303.

32 [43] J.L. Smart, J.A. McCammon, *J. Am. Chem. Soc.* 118 (1996) 2283.

Figures

Figure 1: High resolution core level photoemission spectra of (a) C 1s (b) N 1s (c) Si 2p, taken with a pass energy of 20 eV using monochromatic Al K α monochromatic X-rays (1486.69 eV), with the X-ray source operating at 100 W. The analysis area was a 220 by 220 micron spot. The measurements were carried out in normal emission geometry. The core level peaks are deconvoluted to show the various bonding environments. Data analysis was performed using CasaXPS (www.casaXPS.com). Shirley backgrounds were used in the peak fitting. Core level data were fitted using Gaussian-Lorentzian peaks (30 % Lorentzian).

Figure 2: Tapping-Mode AFM topographical imaging of PECVD deposited APTES coating on silicon wafer in diverse environment: (A) in air, (B) in DI water, (C) in PBS Tween®, (D) in air after washing with DI water and drying in air, (E) in air after washing with PBS Tween® and drying in air. RMS roughness values are also indicated.

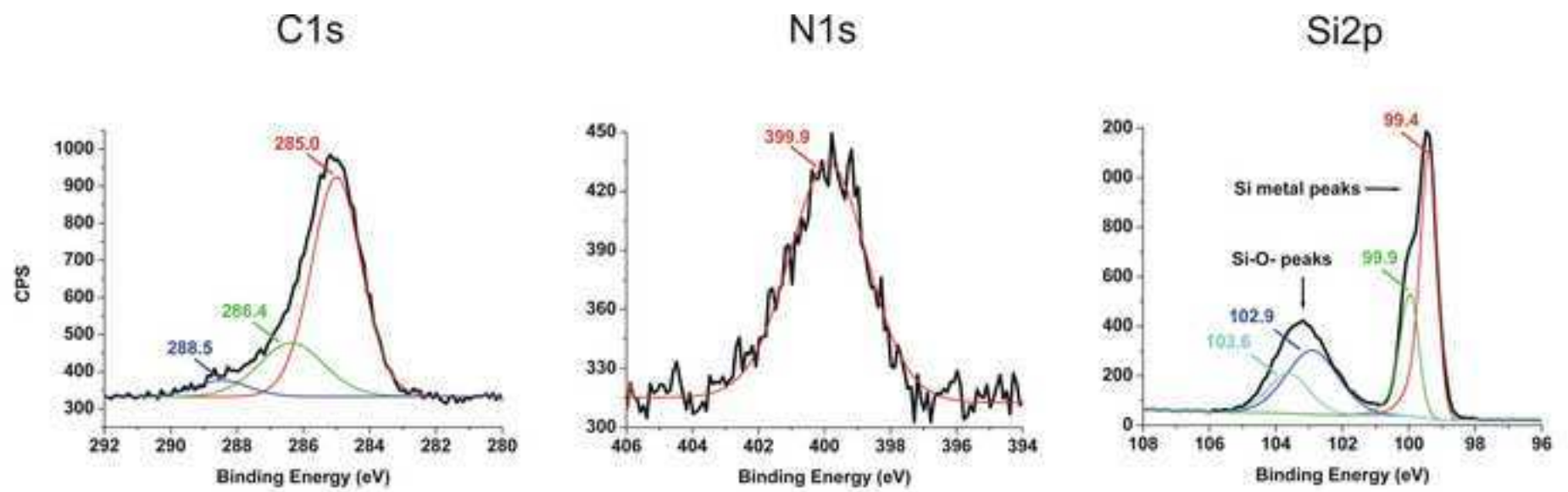
Figure 3: Representative force curves (approach in black and retraction in red) for NH₂ terminated tips and NH₂ modified substrate surface in different pH solutions. Upper number indicates pH of the solution during experiment.

Figure 4: Chemical force titration curve for tip and surface both modified with PECVD deposited APTES coating, acquired under solution of 10⁻² M ionic strength. (The curve has been added as a guide to the eye). Scheme are presenting the proposed interactions of APTES modified tips and APTES modified surface in water at different pH values. (B) Negative cosine of the averaged contact angles of water drops on a silicon surface modified with PECVD deposited APTES as a function of pH

1
2 **Figure 5:** Degree of ionization α_i as a function of the pH calculated on the basis of the
3
4
5 adhesion forces (Fig. 4).
6
7
8
9
10
11
12
13
14
15
16
17
18
19
20
21
22
23
24
25
26
27
28
29
30
31
32
33
34
35
36
37
38
39
40
41
42
43
44
45
46
47
48
49
50
51
52
53
54
55
56
57
58
59
60
61
62
63
64
65

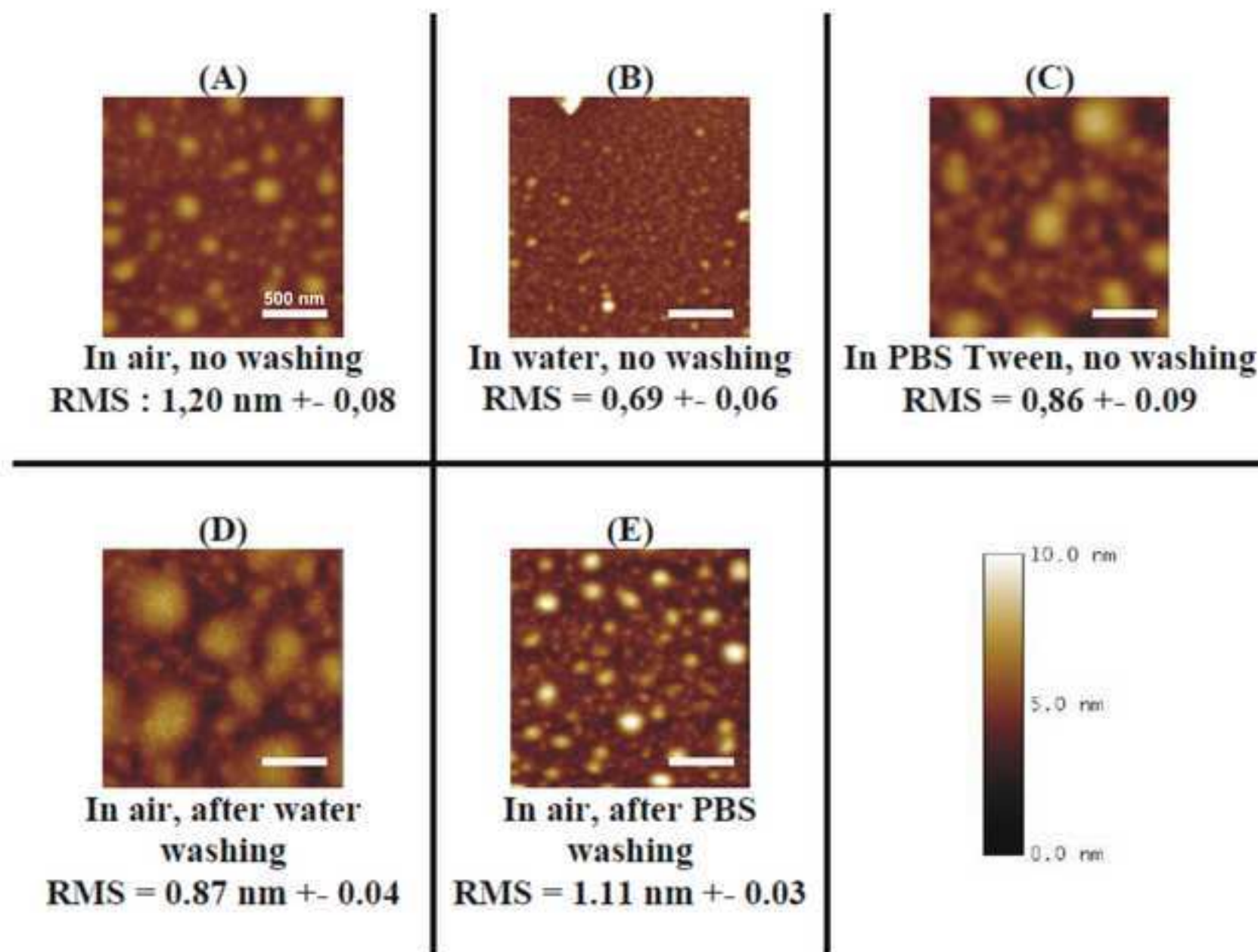
5: Figure 1

[Click here to download high resolution image](#)



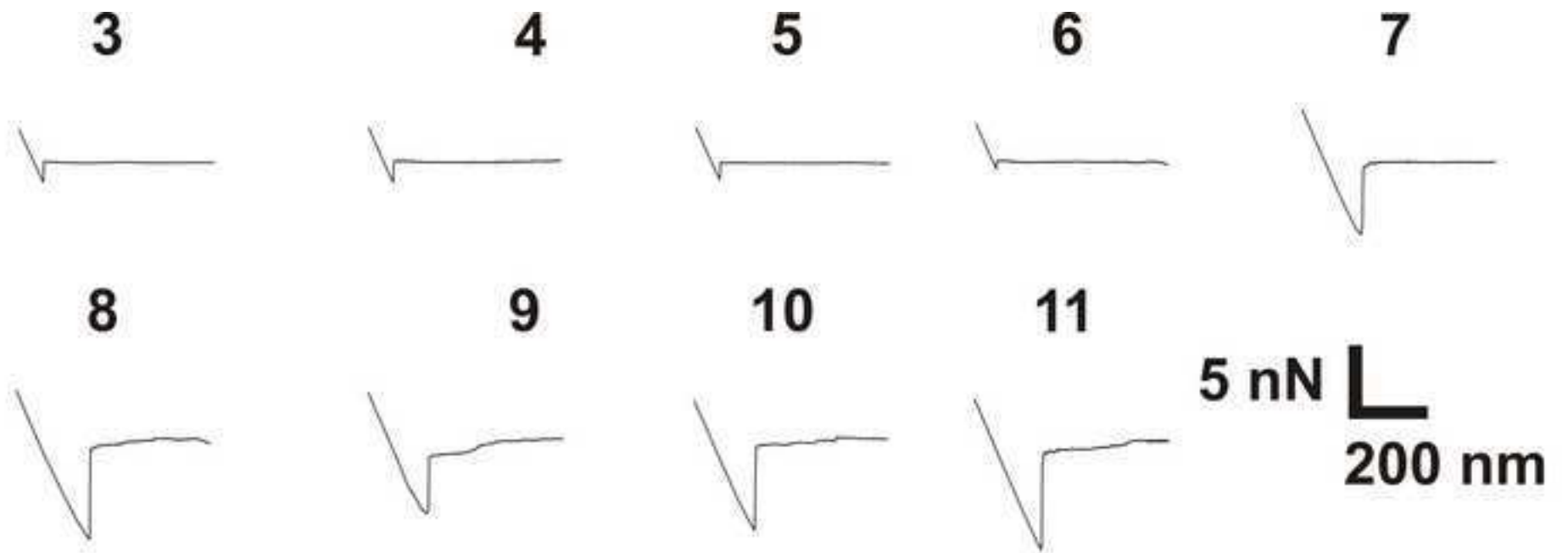
5: Figure 2

[Click here to download high resolution image](#)

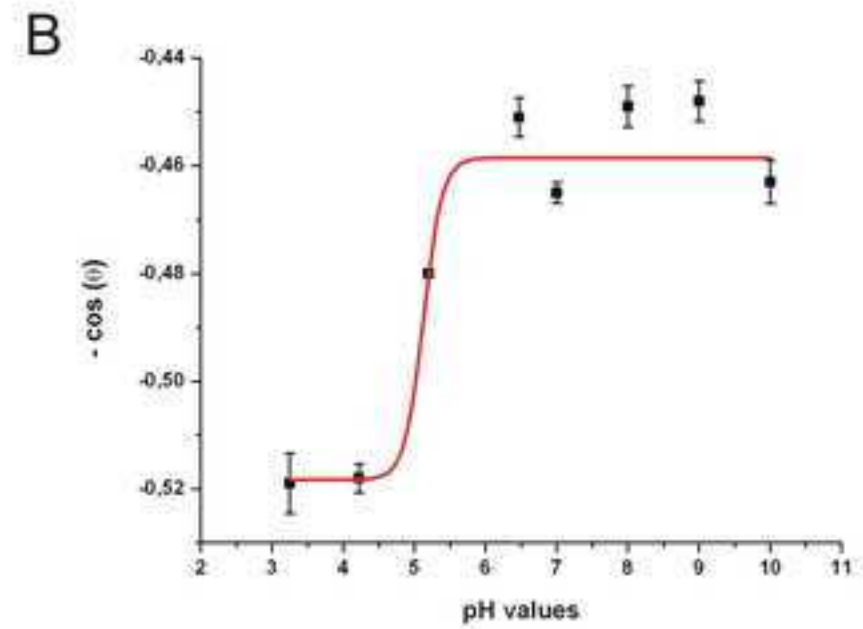
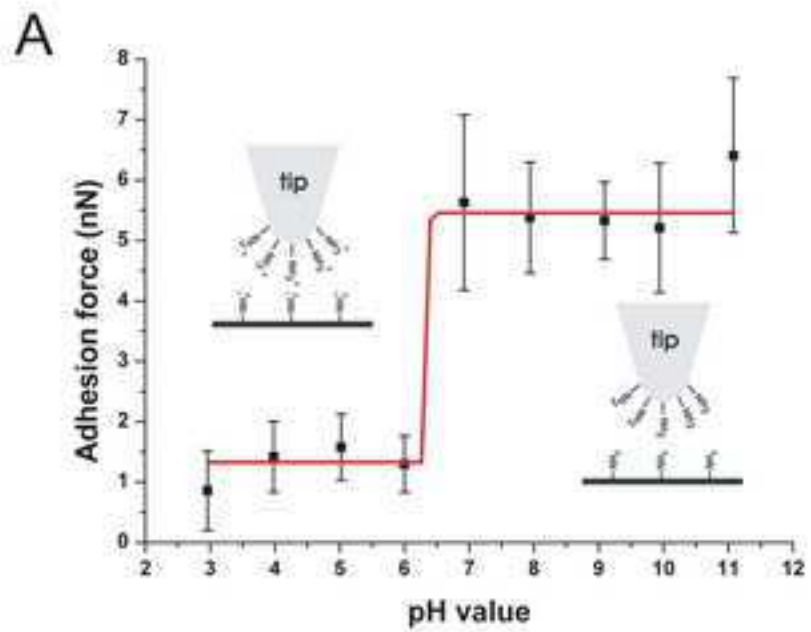


5: Figure 3

[Click here to download high resolution image](#)

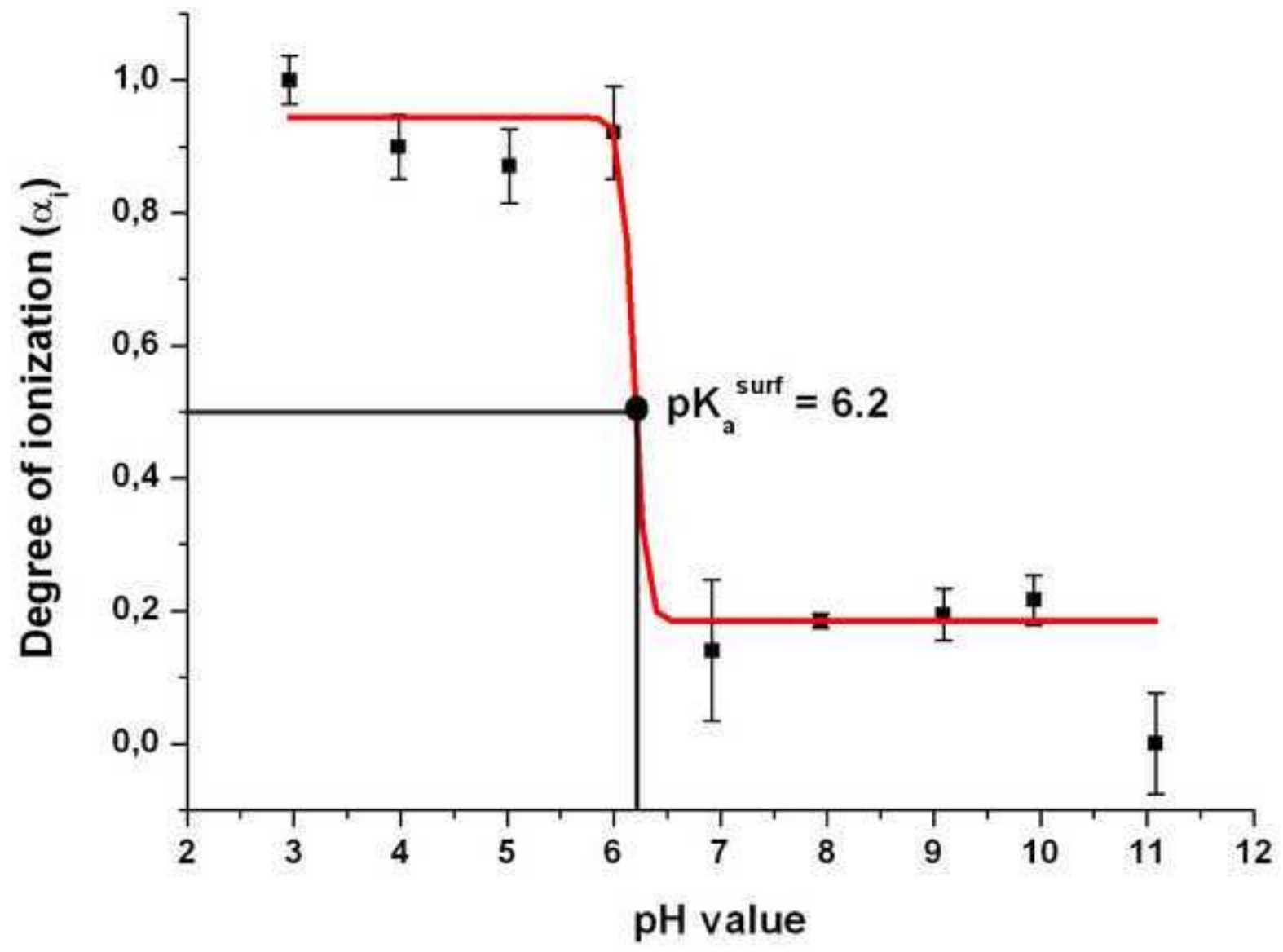


5: Figure 4
[Click here to download high resolution image](#)



5: Figure 5

[Click here to download high resolution image](#)



7: Electronic Supplementary Material (online publication only)

[Click here to download 7: Electronic Supplementary Material \(online publication only\): Supporting Informations.pdf](#)